

Controlled properties of perovskite oxide films by engineering oxygen octahedral rotation

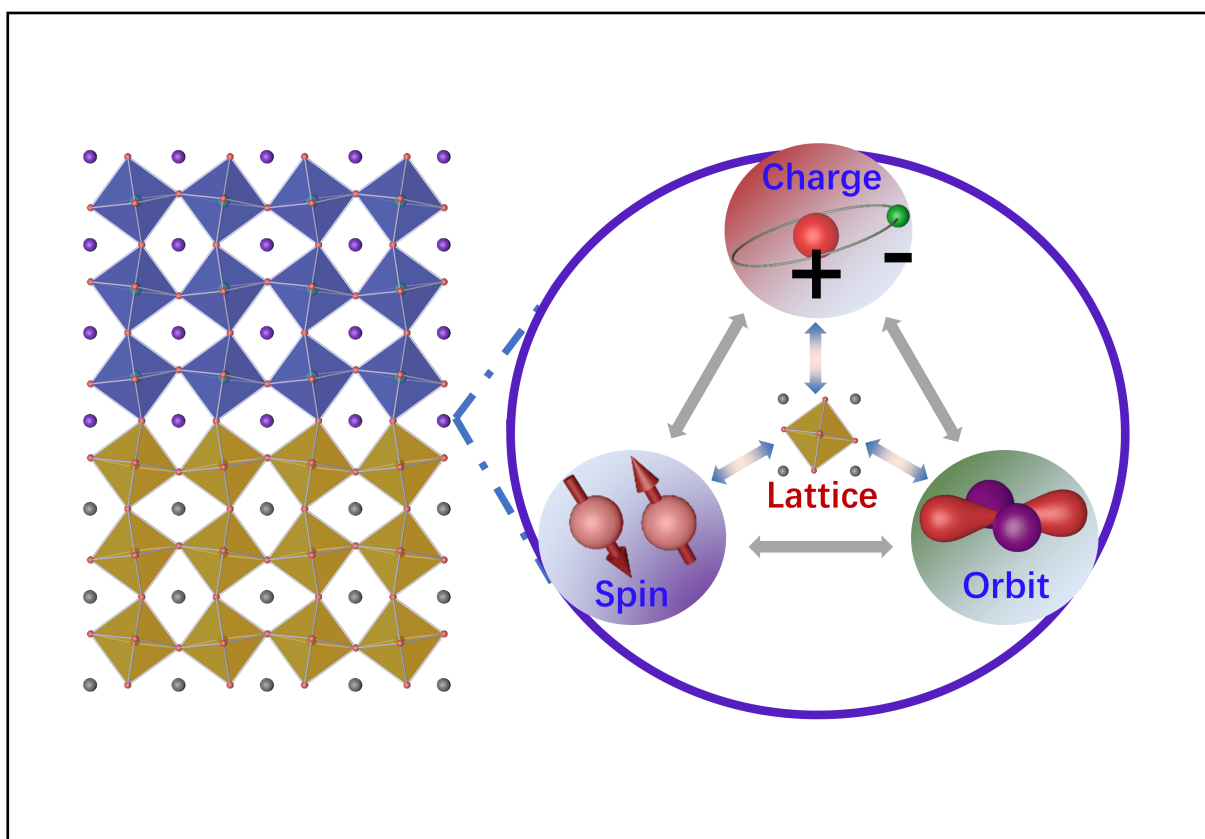
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Graphical abstract



Interaction between oxygen octahedral rotation (lattice) and many degrees of freedom including spin, orbit, and charge.

Public summary

- We review and summarize the structure of perovskite oxides, the characterization methods of oxygen octahedral rotation, as well as the response for transport, electrical polarization, and magnetism.
- Half-order X-ray diffraction and STEM (HAADF and ABF) are two most common techniques to characterize the octahedral rotation.
- Several key issues that need to be solved urgently are proposed to facilitate breakthroughs in octahedral-rotation-based devices.

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Abstract: Complex perovskite oxides exhibit extremely rich physical properties in terms of magnetism, electrical transport, and electrical polarization characteristics due to the competition and coupling of many degrees of freedom. The B-site ions and O ions in perovskite form six-coordinated octahedral units, which are connected at a common vertex toward the basic framework of the perovskite oxide, providing a crucial platform to tailor physical properties. The rotation or distortion of the oxygen octahedra will tip the competing balance, leading to many emergent ground states. To further clarify the subtle relationship between emergent properties and oxide octahedral behavior, this article reviews the structure of perovskite oxides, the characterization methods of oxygen octahedral rotation and the response of transport, electrical polarization and magnetism of several typical perovskite heterostructures to oxygen octahedral rotation modes. With knowledge of how to manipulate the octahedral rotation behavior and regulate the physical properties of perovskite oxides, rationally designing the sample manufacturing process can effectively guide the development and application of novel electronic functional materials and devices.

Keywords: perovskite oxide; interface coupling; oxide octahedral rotation; structural characterization; property regulation

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1 Introduction

Perovskite oxide, with the general chemical formula ABO_3 , has achieved a series of important applications in low-power electronics, information storage, and energy conversion due to its extremely rich physical properties^[1–3]. The d-orbital of the B-site element collaborating with charge, spin, and lattice gives rise to many interesting emergent phenomena, including multiferroic, superconductivity, metal-insulator transition, and charge/spin/orbital order^[4]. Different from conventional semiconductors, perovskite oxide possesses several tunable degrees of freedom in terms of geometric structure, including typical $[BO_6]$ octahedral rotation and distortion. Recent studies have demonstrated a strong correlation between the oxide octahedral rotation (OOR) behavior and lattice vibration mode^[5,6], affording us the ability to tune or design the acoustic and optical properties of a material by OOR. More importantly, the OOR can modify the space symmetry around the heterointerface between different perovskites^[7]. Lattice strain that originates from self-adapting B–O bond length is a significant approach to engineer properties and is a key mechanism to understand interface mismatch as well. However, the B–O–B bond angle changes, driven by symmetry mismatch at a heterointerface, have great potential to modulate the properties of complex oxides. The former dominates the breathing and shape distortion of the octahedra, while the latter induces octahedral rotation or tilt. Both of them can change the bandwidth of the d-band to control the electrical and magnetic properties of a material. Therefore, exploring the way to con-

trol oxygen octahedral rotation and understanding the response of properties to octahedral behavior are crucial for designing novel functional materials and electronic devices.

In recent decades, with the rapid development of advanced thin film preparation and characterization techniques, including molecular beam epitaxy (MBE) and pulsed laser deposition (PLD), many atomic-level precise epitaxial heterostructures have been achieved. In fact, changing the interfacial octahedral geometry as a class of significant strategies toward interfacial emergent phenomena has gained great attention in recent years. A series of emergent phenomena^[8–11], such as interfacial metallicity, superconductivity, and ferromagnetism which are not energetically favored in bulk materials, were observed at oxide interfaces. First-principles calculations demonstrated that the octahedral rotation pattern can diffuse into the interior of an epitaxial layer due to interfacial bonding, which finally produces different symmetry from the bulk counterpart^[12]. Experimentally, octahedral coupling and rotation at a heterointerface were observed by some modern characterization methods, such as synchrotron radiation half-order X-ray diffraction (HO-XRD) and high-resolution scanning transmission electron microscopy (STEM)^[13–15]. Realizing oxygen octahedral rotation in oxide films utilizing interfacial bonding, therefore, is considered to be a preferred strategy for tuning the physical properties of oxide systems, including but not limited to ferroelectric polarization arising from broken inversion symmetry, magnetic and transport modulation caused by the bond angle change, and the

indicate equal rotation. For example, the mode (abb) means equal rotation around axes [010] and [001] but larger than that around [100]. Mode (abc) represents different rotation amplitudes around axis [100], [010], and [001]. OOR phases are denoted by superscripts “+”, “−”, and “0”. Here, the superscript “+” indicates that all octahedra rotate in phase, i.e., in the same direction around a given crystal axis, and the superscript “−” indicates that all octahedra rotate out of phase, i.e., neighboring octahedra rotate in the opposite direction above a given axis. The superscript “0” indicates that there is no tilt.

According to the Glazer notation, the ideal cubic perovskite has a rotation mode ($a^0a^0a^0$). To maintain the connectivity of the octahedra, two rules should be enforced for a rotation network. As shown in Fig. 1b, opposite rotation signs are required about the tilt axis normal to their shared plane, otherwise, the connectivity of the octahedra is broken. On the other hand, the rotation signs of adjacent octahedra around the shared axis are either in-phase or out-of-phase rotation. For example, in an ($a^+a^0a^0$) rotation system, all octahedra around the [100] axis possess the same sign of rotation but no rotation around others to comply with the requirement of in-phase rotation. If the rotation behavior is out-of-phase between two adjacent octahedra, then it will have opposite rotation signs ($a^-a^0a^0$). With these two rules, the rotation networks can be produced for the ($a^+a^0a^0$) and ($a^-a^0a^0$) single tilt systems, as shown in Fig. 1c.

To study the local characterization of interfacial octahedral networks, it is necessary to accurately describe the rotation of a single octahedron. A new notation [x, y, z] (where x, y, z take “+”, “−”, or “0”) was proposed to describe the rotation of a single octahedron in our previous work^[31]. Counterclockwise rotation around a specific pseudocubic axis is defined as “+”, clockwise rotation is defined as “−”, and no rotation is defined as “0” for a single oxygen octahedron. Therefore, for the octahedral network on the left in Fig. 1d, the front and rear octahedral arrays have exactly the same behavior considering only the in-phase rotation around the [100] axis. It should be noted that the superscript in the Glazer notation is used to represent the relative rotation direction of adjacent octahedra while the notation here is used to describe the absolute rotation direction of a single oxygen octahedron.

Using this notation, different octahedral behaviors described by the same Glazer notation can be reflected. As shown in Fig. 1d, ($a^+a^+a^+$) can give two kinds of octahedral networks [$---$] and [$- - +$], which correspond to two mirror-symmetric orthogonal structures with unit cell angles α and $180^\circ - \alpha$, respectively. The $\text{NdGaO}_3/\text{NGO}$ crystal is an example with two domain structures indicated by $\alpha < 90^\circ$ and $\alpha > 90^\circ$. In addition, ($a^-a^-a^-$) gives a total of four octahedral networks, namely [$---$], [$+ - -$], [$- - +$], and [$+ - +$], and these octahedral networks are grouped into two pairs of rhombohedral structures, in which each pair is mirror isomeric to each other (Fig. 1e). At the perovskite interface with the same symmetry, such as $\text{CaTiO}_3/\text{NdGaO}_3$ and $\text{SrRuO}_3/\text{DyScO}_3$, the requirement of matched OOR modes results in a single domain structure^[31,32]. For heterostructure systems with different symmetries, the symmetry of the substrate can be introduced in the film through interface OOR coupling. Using

$\text{La}_{2/3}\text{Sr}_{1/3}\text{MnO}_3$ (LSMO) thin films epitaxially grown on (110) NGO substrates as an example^[33], the OOR coupling at the interface will lead to the rearrangement of oxygen rotation in LSMO (see Fig. 2a). The OOR of LSMO possesses the same rotation phases as NGO; as a result, the LSMO which in bulk is ($a^+a^+a^+$) becomes ($c^+a^+a^+$). Due to the interface reconstruction of symmetry, the ultrathin LSMO possesses dramatically different magnetic anisotropy than the thick counterpart. Additionally, introducing a single unit cell of STO can locally modify the symmetry by tailoring the interface decay distance of the OOR (see Fig. 2b).

2.3 Characterization of oxygen octahedral rotation

With the rapid development of theoretical packets and experimental techniques, precise characterization of the modes and amplitudes of OOR has become feasible. Theoretical calculations revealed the details of OOR intuitively by optimizing the interface structure to predict the corresponding physical properties^[34–37]. In experiments, the oxygen octahedral rotation can be characterized indirectly or directly by HO-XRD and STEM (including annular bright field image (ABF) and high-angle annular dark field image (HAADF))^[13,32,33,38–40], respectively. However, due to the small scattering factor of ligand and oxygen, synchrotron X-ray, or aberration-corrected STEM is usually required to ensure high resolution.

The X-ray diffraction peaks of crystals are integers in the octahedral network without rotation, but half-integer peaks appear for the rotational system. In fact, an additional second-order period with a double lattice constant is added to the interfacial octahedral array, according to the two rules mentioned above. The corresponding half-integer diffraction peaks can be observed using the HO-XRD technique, where the position of the peak is used to determine the rotation mode, and the peak intensity is used to estimate the magnitude of the rotation^[7,29]. Specifically, when the oxygen octahedra show in-phase rotation around the pseudocubic axis [100], [010], or [001], 1/2 (even, odd, odd), 1/2 (odd, even, odd), or 1/2 (odd, odd, even) diffraction peaks will appear in the scan patterns. However, only 1/2 (odd, odd, odd) diffraction peaks are present if the OOR mode is out-of-phase. Kan et al.^[41] systematically characterized the OOR in SrRuO_3 (SRO)/NGO heterostructures from a three-dimensional perspective using HO-XRD and quantified the dependence between HO-XRD intensity and OOR amplitude. Lee et al.^[13] realized the OOR amplitude regulation of the functional layer BFO with the ($a^-b^-c^-$) mode through the symmetry design of the template SRO (T-SRO and M-SRO).

However, HO-XRD can solely reflect the global structural information at the penetration depth scale. Therefore, it cannot be used for characterizing the octahedral rotation patterns of different compounds in a multilayer oxide. To parse the OOR spatially, Chen et al.^[42] recently developed an A-site ionic symmetry correlated X-ray reciprocal space mapping (RSM) technique. The out-of-phase OOR removes the orthogonality between the corresponding axes of the cation lattice, leading to the asymmetric diffraction pattern recorded by RSM. For example, in a system with the “+ − −” mode (only the rotation mode index is shown here), the orthogonality between the b axis and c axis is lifted. As shown in

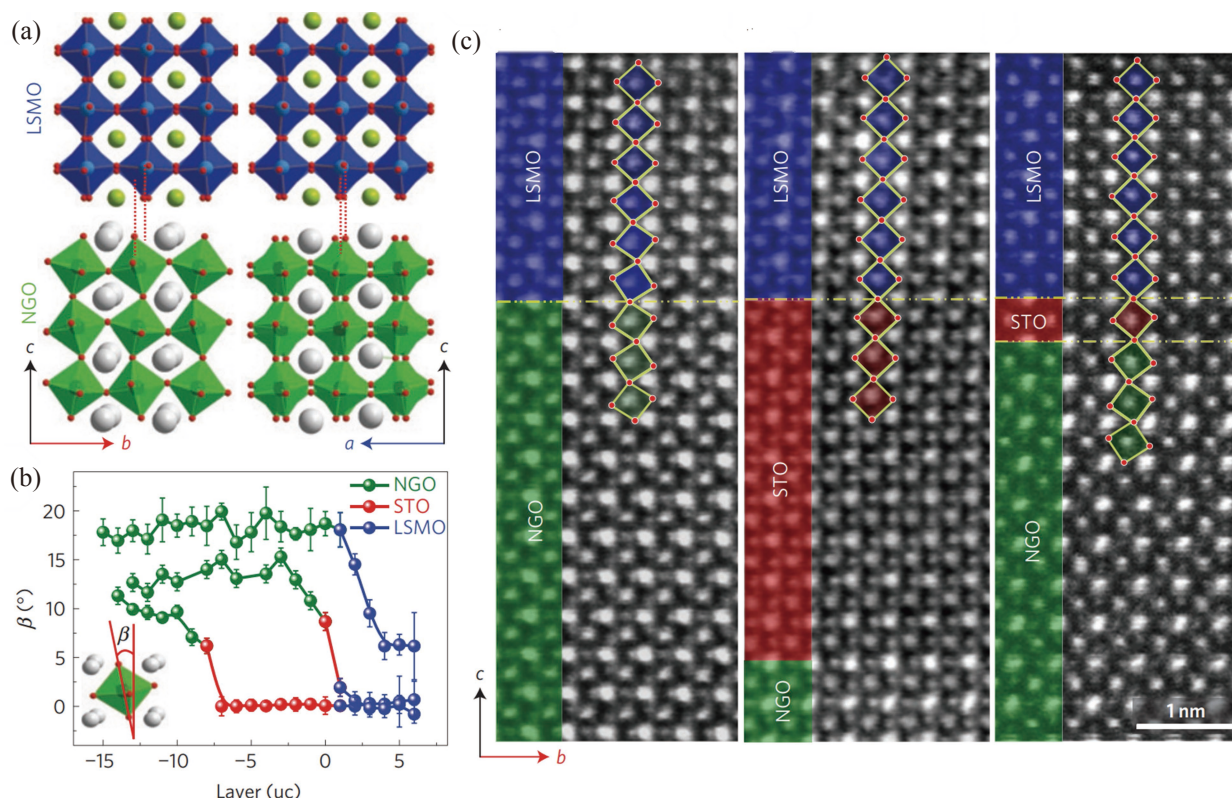


Fig. 2. Oxygen octahedral coupling at the heterointerface between perovskite oxides. (a) Schematic diagram of octahedral rotation in LSMO and NGO interface. (b) Layer-position-dependent mean octahedral tilt angle (β) in LSMO/NGO heterostructures with and without a STO buffer layer. The data for the non-buffered sample are shifted upwards by 6° for clarity. (c) It shows ABF-STEM images of LSMO/NGO, LSMO/STO₁/NGO and LSMO/STO₁/NGO heterostructures. Figure taken from Ref. [33].

Fig. 3a, peaks (103) and (-103) show symmetric diffraction patterns for axes a and c with orthogonality preserved. In contrast, an asymmetric counterpart was shown due to the destroyed orthogonality between the b and c axes. More importantly, in the $\text{La}_{2/3}\text{Sr}_{1/3}\text{MnO}_3$ (LSMO)/ PbTiO_3 (PTO)/LSMO/(110) NGO heterostructure, the RSM can identify different octahedral rotations for each LSMO layer, unraveling the appearance of multiple Curie temperatures and coercive fields. The schematic diagrams of different heterostructures and the corresponding HO-XRD spectra are shown in Fig. 3b and 3c.

Compared with Fig. 3c, the origin of the weak and wide blue diffraction peaks in Fig. 3b cannot be identified. At this point, the RSM based on the cation lattice showed its unique advantages in matching these diffraction peaks to the corresponding layer. Fig. 3d presents the RSM patterns around different crystal planes. The LSMO-1 layer with a larger L reveals symmetric (± 103) diffraction peaks and asymmetrical (0 ± 13) diffraction peaks, thus revealing the monoclinic ion lattice (i.e., $\alpha \neq 90^\circ, \beta = \gamma = 90^\circ$) and the “+ − −” rotation mode. The RSM pattern of the LSMO-2 layer (see the orange arrows) was observed at a lower L index, showing symmetric (± 103) and (0 ± 13) peaks, thus it has a “000” mode with $\alpha = \beta = \gamma = 90^\circ$ in the cationic lattice. In addition, the PTO layer (indicated by dotted green lines) has symmetric (± 103) and (0 ± 13) diffraction patterns, indicating that the “000” mode of the bulk is preserved in the film. In conclusion, RSM is used to achieve the qualitative characterization of the octahedral rotation mode of the $(\text{LSMO})_9/(\text{PTO})_{12}/(\text{LSMO})_9/(110)\text{NGO}$ heterostructure based on the correlation between the cationic

lattice and octahedral rotation mode, which provides a new research method for OOR in complex multilayer heterostructures.

STEM is still the mainstream means to characterize the OOR due to its extremely intuitive and quantifiable experimental results^[32, 33, 40, 43]. Fig. 2c shows the high-resolution ABF-STEM image at the LSMO/STO/(110)NGO heterointerface^[33], which exhibits the in-phase rotation of the $[\text{GaO}_6]$ octahedra around the a -axis direction. In addition, detecting the OOR globally is appropriate by changing the slicing direction of the sample^[32, 44]. Here, the ABF results show that the LSMO films exhibit an in-phase OOR mode at the interface, consistent with the $[\text{GaO}_6]$ octahedra in the NGO substrate. The rotational amplitude exhibits a continuous attenuation from the interface to the interior of the film, disappearing rapidly when the thickness is greater than 4 unit cells (u.c.) Interestingly, inserting a nonrotated ($a^0a^0a^0$) STO layer in the LSMO/NGO heterostructure made the OOR amplitude decay rapidly and disappear after 2 u.c. (as shown in the middle panel of Fig. 2c). Using STEM to detect interfacial structures, one can “patch” the clear outline of the oxygen octahedra.

In general, HO-XRD and STEM, as two techniques to characterize OOR, have received extensive attention due to their intuitive measurement results. However, these methods still have some limitations. For example, HO-XRD can only reflect the global OOR without spatial resolution, and a direct measurement of OOR requires highly sophisticated experimental techniques, such as the synchrotron light source. On the other hand, the aberration corrector should be equipped in

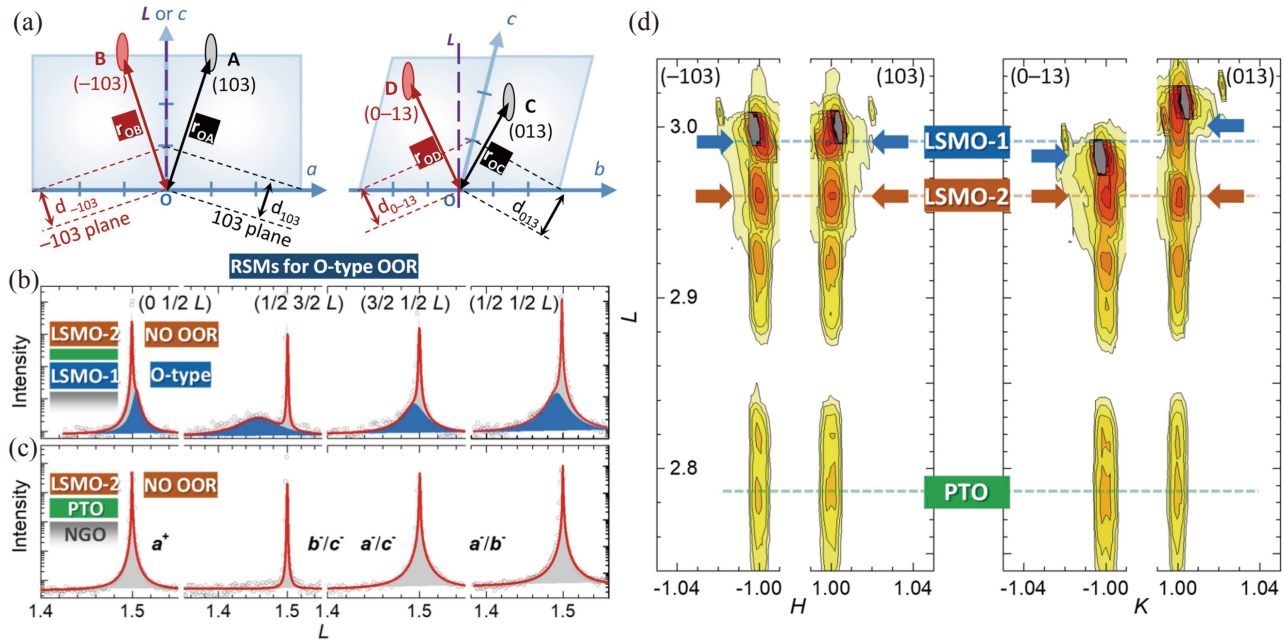


Fig. 3. RSM characterization of oxygen octahedral rotation. (a) The sketches of the RSM with symmetric and asymmetric reflections, where r_{OA} , r_{OB} , r_{OC} and r_{OD} represent reciprocal vectors. (b) and (c) display different half-order X-ray diffraction spectrum corresponding to the heterostructures, and the blue part in (b) is obtained by peak fitting. (d) The RSMs of LSMO/PTO/LSMO/NGO along different diffraction faces. Figure taken from Ref. [42].

STEM to improve the imaging resolution. Therefore, it is necessary to develop new technologies (such as RSM here) for determining octahedral rotation^[42]. In addition, other characterization techniques, including extended X-ray absorption fine structure spectroscopy (EXAFS)^[45–49], coherent Bragg diffraction rod analysis (CBRA)^[50, 51], Raman scattering spectroscopy^[15, 6, 52–54], also play an important role in the direct or indirect OOR measurement.

3 Tailoring properties by octahedral rotation

3.1 Octahedral distortion

Chemical doping or external stress can lead to the distortion of the $[BO_6]$ octahedra in perovskite oxides, including size distortion and shape distortion, thereby affecting properties. The distortion that the B–O–B bond angle remains constant and the B–O bond length increases or decreases by the same degree is called size-distortion (Q_1 mode), also known as the “breathing effect” of the octahedra. This will cause a network with the same octahedra shape but different sizes, which can induce charge disproportionation of B-site ions through the B–O electrostatic interaction, thereby forming a new B-site ion valence state and charge order^[55–58], giving rise to many novel phenomena, such as Mott insulator^[59, 60], metal-insulator transition^[61, 62], ferroelectricity^[63, 64], and ferromagnetism^[55]. Another type of octahedral distortion, known as shape distortion, is characterized by the fact that the B–O–B bond angles do not change significantly, but the bond lengths no longer remain constant. Generally, the change in bond lengths for in-plane and out-of-plane have opposite trends, which are called the Q_2 mode or Q_3 mode, also known as the Jahn-Teller distortion. Shape distortion can induce the polarization of the B-site d orbital through the electron phonon interaction, lifting the degeneracy of the e_g orbital or the t_{2g} orbital to form an or-

bitar order, which is very common in 3d manganese oxides^[65–67]. In addition, perovskite oxides composed of transition metal elements with d^0 electrons (such as Ti^{4+}) or main-group elements with $6s^2$ electrons (such as Pb and Bi) will spontaneously generate ferroelectric polarization due to the broken inversion symmetry, which is also classified as an octahedral shape distortion^[68, 69].

3.2 Octahedral rotation

Lattice size and symmetry match are two factors that need to be considered first during film epitaxy. To maintain a continuous three-dimensional oxygen octahedra structure at the heterointerface, the substrate needs to impose geometric constraints on the oxide film, thereby affecting the rotation amplitude of the octahedra. In fact, the symmetry induced by the octahedral coupling can penetrate the entire epitaxial film if the growth fashion of coherent epitaxy is maintained^[70]. Recently, interesting physical phenomena, such as the metal-insulator transition, antiferromagnetic-paramagnetic phase transitions, and polar metal states modulated by $[NiO_6]$ octahedral rotation, have been reported in nickelate superlattices^[40, 71–73]. Controllable modulation of the magnetization, anisotropy and other properties can also be achieved by tailoring the OOR mode and amplitude^[16, 33, 74, 75]. Expectedly, the B–O–B bond angle change caused by the OOR can significantly enhance the Dzyaloshinskii-Moriya interaction (DMI) due to broken inversion symmetry, thereby leading to a topological Hall effect^[76–78]. In addition, the presence of the OOR in paraelectric oxides can also lead to metastable ferroelectric order and complex electrical polarization states^[39, 79, 80].

3.2.1 Modulating electrical properties

3.2.1.1 Metal-insulator transition

The basic electric transition of the simplest correlated electronic system is jointly characterized by the Coulomb repulsion potential and electronic hopping term, where the d elec-

tron hopping between two B-sites is mediated by the O 2p orbital. OOR changes the B–O–B bond angle, which tailors the overlap integral between the d orbital and O 2p orbital^[81]. Specifically, when the bond angle of B–O–B deviates from 180°, the hopping constant decreases and the d electron band becomes narrow. A larger tilt usually induces a narrower band width, so eventually, a gap is opened around the Fermi level and the metal-insulator transition (MIT) occurs. The MIT behavior^[40, 72, 73, 82] has been tuned precisely by constructing artificial superlattices to control the rotation modes and amplitudes, which has been widely studied in nickelate oxides.

Tunable transport behavior and magnetism ground state were reported in a rare-earth nickelate SmNiO_3 (SNO) by controlling the OOR^[72], where LaFeO_3 (LFO), LaCrO_3 (LCO), and LaNiO_3 (LNO) with identical symmetry and different tilt magnitudes were used as templates. Fig. 4a shows the tunable conductance and metal-insulator transition temperature T_{MIT} with varying thickness (n) of the SNO layer in different $\text{LFO}_1\text{-SNO}_n$ ($n = 4\text{--}10$) superlattices. In particular, the T_{MIT} of the $\text{LFO}_1\text{-SNO}_4$ superlattice is only 78 K, which is much lower than that of SNO_{30} (356 K). As the thickness of the SNO layer increases, the structural modulation effect of the LFO_1 layer becomes weaker, driving T_{MIT} toward higher temperatures and then approaching that of the SNO_{30} film. X-ray absorption spectroscopy (XAS) of the Ni-L_{2,3} edge illustrated the intrinsic mechanism of T_{MIT} (Fig. 4d). The splitting of the Ni L edge is suggested to depend on both the magnitude of the breathing mode distortion and the size of the Ni–O–Ni hopping interaction. A smaller splitting energy indicates a

smaller Ni–O–Ni interaction and a smaller breathing distortion. On the other hand, as shown in Fig. 4b, SNO_4 -based superlattices constructed with different tilt templates, LCO and LNO, also exhibited lower T_{MIT} than SNO_{30} . Interestingly, the LNO bulk has a smaller octahedral tilt (5.3°) than LFO (6.8°), while $\text{LNO}_1\text{-SNO}_4$ exhibits higher T_{MIT} than $\text{LFO}_1\text{-SNO}_4$. This is because LNO is subjected to a tensile stress, resulting in a smaller out-of-plane lattice and a larger rotation amplitude of octahedra. In contrast, LFO is under compressive stress, so the $[\text{NiO}_6]$ tilt angle will decrease. Furthermore, the Néel temperatures T_N of different superlattices are observed to be positively correlated with T_{MIT} by resonant magnetic diffraction (RMD), as shown in Fig. 4c. These results demonstrated the remote control of the ground state properties of nickelates through interfacial OOR modulation. The phase diagram shown in Fig. 4e reveals the correlation between the microscope structure and the physical states, which supplies new perspectives for the controllable design of novel quantum materials. Similarly, Chen et al.^[40] observed tunable metal-insulator transition and antiferromagnetic-paramagnetic transition behaviors in $\text{NdNiO}_3/\text{SrTiO}_3$ superlattices by changing the thickness of NdNiO_3 . In addition, ionic liquid gating is also an effective method to modulate the octahedra rotation, as reported by Liu et al.^[82] in WO_3 films. Dong et al.^[73] observed an almost zero thermal hysteresis effect at T_{MIT} in a $\text{NdNiO}_3/\text{NGO}$ heterostructure by reducing the Ni–O–Ni bond angle through interface octahedral coupling. Notably, the d-orbital polarization induced by octahedral rotation may give rise to MIT, which plays a significant role similar to the

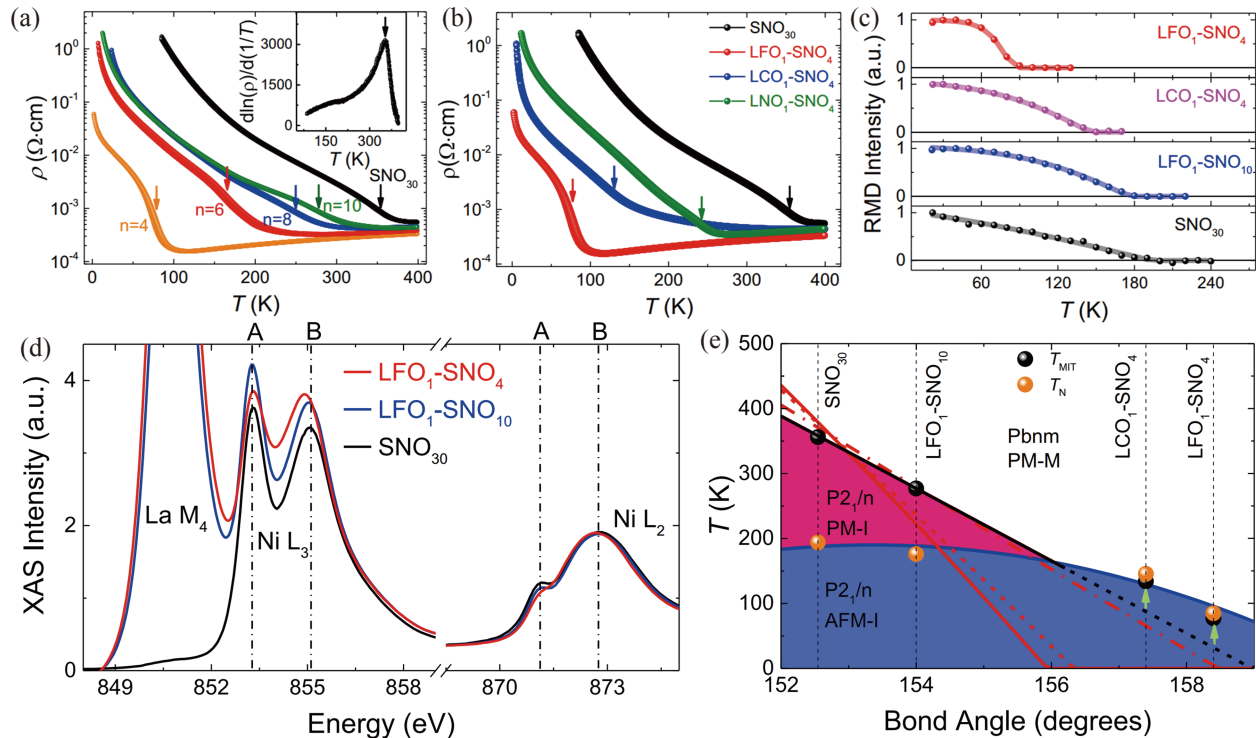


Fig. 4. MIT in nickelate superlattices triggered by oxygen octahedral coupling. (a) ρ - T curves of $\text{LFO}_1\text{-SNO}_n$ ($n = 4\text{--}10$) superlattices and 30 u.c. SNO film, and the inset shows the first derivative $d\ln\rho/d(1/T)$ of the SNO_{30} film. (b) ρ - T curves of SNO_4 superlattices constructing with LFO, LCO and LNO. (c) Temperature dependent intensity of $(1/4, 1/4, 1/4)$ magnetic Bragg reflection peak. (d) X-ray absorption spectra (XAS) of Ni L_{2,3} edge of nickelate superlattices with different thicknesses at 22 K. (e) Temperature phase diagram of nickelate superlattices as a function of the mean Ni–O–Ni bond angle. Figure taken from Ref. [72].

OOA amplitude^[83], providing a new theoretical basis for tuning physical properties.

3.2.1.2 Magnetic transport modulation

Double exchange and the Stoner model are the two most important theories for understanding the ferromagnetism in oxides^[84, 85]. Typical ferromagnetic oxides, 3d manganate and 4d ruthenate, have a finite electronic density of states at the Fermi level, revealing good metallic behavior. These perovskite oxides possess fascinating properties, such as a giant magnetoresistance effect, anomalous Hall effect, and topological Hall effect^[62, 76, 77, 86], which can be tuned and modified by manipulating the delicate coupling of spin, orbit, charge, and lattice.

As a lattice-level modulation strategy, interfacial OOR coupling has attracted much attention in electro and magnet transport in recent years. Zhang et al.^[86] realized the low-temperature irreversible magnetoresistance effect in $\text{Pr}_{0.67}\text{Sr}_{0.33}\text{MnO}_3$ through OOR amplitude modulation at the substrate-film heterointerface. The topological Hall effect (THE) is a significant transport feature of chiral spin textures in real space, such as skyrmions^[87, 88]. Ziese et al.^[76] prepared $\text{SrRuO}_3/\text{Pr}_{0.7}\text{Ca}_{0.3}\text{MnO}_3$ (PCMO) superlattices to explore the origin of the THE in SRO/FMO (ferromagnetic oxide) systems. Interestingly, their study pointed out that PCMO can induce the $[\text{RuO}_6]$ OOR in the interfacial layer, resulting in different symmetry from the bulk. As is known, the magnitude and sign of anomalous Hall resistance are closely related to lattice structure; thus, the global contribution from multichannel anomalous Hall signals with opposite signs can imitate anomalous Hall signals with topological characteristics. Qin et al.^[77] observed the THE in single SRO films less than 10 nm, pointing out that a heavy metal oxide capping layer (such as SrIrO_3) is not necessary for the topological Hall signal. Additionally, the temperature and magnetic field windows for THE can be tuned by changing the oxygen partial pressure, which is attributed to $[\text{RuO}_6]$ octahedral rotation.

Not just OOR, however, structural phases transition, defects^[15, 89], and multiple rotation modes at the heterointerface can also be induced by varying oxygen partial pressure, so OOR is just a handwaving origin of the THE here. In view of this, Gu et al.^[78] prepared $\text{SRO}_M/\text{STO}(001)$ (where $M = 5\text{--}10$ u.c.) and $\text{SRO}_N/\text{BTO}_N/\text{STO}(001)$ (where $N = 2\text{--}4$ u.c.) heterojunctions to clarify the correlation between THE and OOR. Fig. 5a shows the geometric analysis of interfacial oxygen octahedra. The transport results showed that THE can be observed in the $\text{SRO}_M/\text{STO}(001)$ heterostructure with $M < 10$ u.c., especially in the sample $\text{SRO}_8/\text{STO}(001)$ with $M = 8$ u.c. (see Fig. 5b, left). As a comparison, the counterparts buffered by N u.c. BaTiO_3 (BTO) were prepared. Interestingly, the THE completely disappeared when $N > 2$ u.c., while a weak THE was reproduced in the heterojunction with $N = 2$ u.c. (Fig. 5b, right). HAADF-STEM and ABF-STEM were further utilized to analyze the OOR. As shown in Fig. 5a, the $[\text{RuO}_6]$ octahedra at the $\text{SRO}_8/\text{STO}(001)$ heterointerface have an OOR angle of $\sim 3^\circ$ and decay rapidly away from the interface. Obviously, the symmetry difference between the interface and inside leads to inversion symmetry breaking near the interface, which effectively increases the DMI, thus enhancing the topological Hall signal. Additionally, the OOR was

effectively suppressed by inserting buffer layer BTO with larger radius A-site ions, so it showed a decreased topological Hall signal. In addition to interfacial bonding, Lin et al.^[90] demonstrated tunable OOR by switching the structure of the proximity layer (planar $\leftrightarrow$ chain) utilizing the thickness sensitivity of the SrCuO_2 (SCO) geometry. By constructing SCO/SRO/SCO sandwiches with different SCO thicknesses, two different OOR modes of $[\text{RuO}_6]$ octahedra were realized at the interfaces, resulting in the spin state changes of Ru at the interfaces as well as the hybrid of Ru 4d and O 2p, thereby greatly modulating the magnetic resistance and anomalous Hall resistance.

3.2.1.3 Electric polarization modulation

Symmetry propagation induced by the OOR has demonstrated many strong impacts on the transport behavior of complex oxide films as mentioned above. The highly insulating prototypical ferroelectric oxides, however, typically for BaTiO_3 and PbTiO_3 , have no octahedral rotations. On the other hand, perovskites with OOR can exhibit conductance but are not polar or ferroelectric. This fact seems to imply incompatibility between the OOR and ferroelectric polarization. However, Kim et al.^[79] found $[\text{TiO}_6]$ octahedral rotation-related metastable room temperature ferroelectricity in CaTiO_3 by interfacing with a LaAlO_3 layer, which was further verified by DFT calculations. Similarly, Pramanick et al.^[91] realized OOR mode ordering ($a^-a^-a^-$) by applying an electric field to the 200 nm thick polycrystalline ferroelectric $\text{Na}_{1/2}\text{Bi}_{1/2}\text{TiO}_3$ (NBT). The two examples have already shown the fact that OOR and ferroelectric polarization coexist. Benedek et al.^[92] pointed out that the OOR itself generally does not quench B-site ion ferroelectric polarization, but the accompanying A-site anti-polar displacements can play a crucial role in suppressing the ferroelectricity in $Pnma$ or other space groups that allow rotation distortions. When A-site distortion is absent, many perovskites would adopt the $R3c$ space group, which is allowed to exhibit ferroelectricity.

Interestingly, an electric polarization rotation pattern, a novel emergent ferroelectric structure induced by interfacial OOR coupling, was observed in the PTO/STO heterojunction^[39]. HAADF-STEM clearly demonstrates the rotating electric polarization in PTO, as shown in Fig. 6a. Generally, many different polarization modes can be evolved in PTO films due to the depolarization field. However, it can be ruled out by the counterpart, the Nb:STO substrate with good conductivity. Furthermore, the authors used ABF-STEM to reveal the displacement $\delta_{\text{Ti-O}}$ of Ti^{4+} in both the in-plane and out-of-plane directions (Fig. 6b and 6c). The displacement orientation varies with thickness, thus exhibiting rotational electric polarization in the PTO. Their DFT calculations (see Fig. 6d), as well as earlier theoretical predictions^[36], indicated that the rotational electric polarization is related to the antiferroelectric distortion (AFD) caused by in- and out-of-plane OOR. The ferroelectric PTO without AFD (Model A) showed normal polarization, while that with AFD (Model B) showed a rotational pattern. In addition to electric polarization modulation, Geng et al.^[93] also observed a ferroelectric-antiferroelectric phase transition mediated by OOR coupling in an ultrathin BiFeO_3 system.

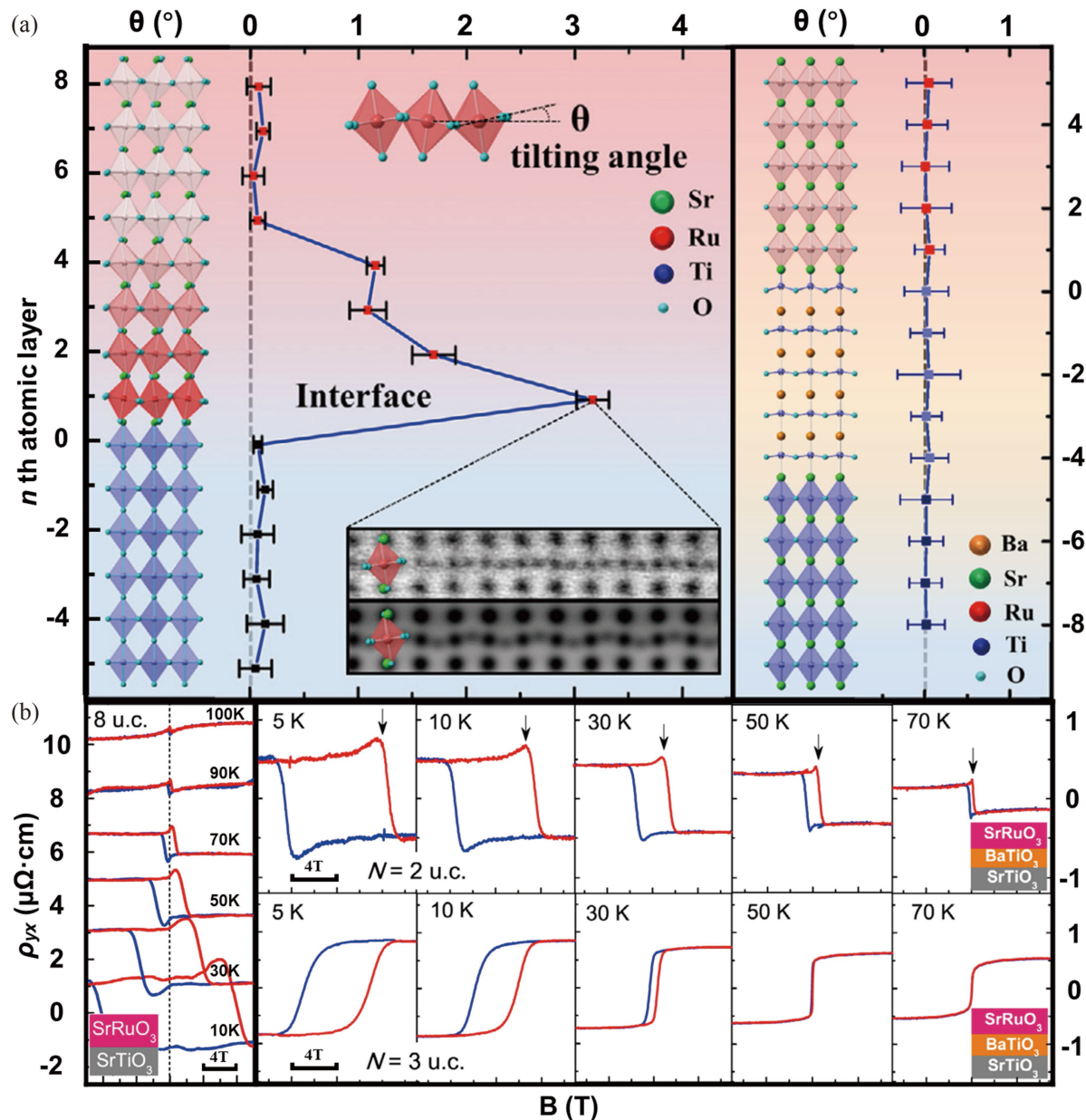


Fig. 5. Octahedral rotation tailoring topological Hall effect. (a) The left figure shows the sketch of the octahedra configuration at the SRO/STO hetero-interface and the statistical results of rotation angle, and the inset respectively show the $[\text{RuO}_6]$ octahedral-rotation ABF image at the first layer of the interface and the simulation results. The figure on the right of the panel shows the statistics result of the rotation angle of the octahedron after inserting the 4 u.c. BTO. (b) The left picture shows the anomalous Hall resistance (AHR) of SRO (8 u.c.)/STO heterostructure at different temperatures, and the right one shows the AHR curve of SRO₈/BTO_N ($N = 2, 3$)/STO at varying temperatures. Figure taken from Ref. [78].

3.2.2 Modulating magnetism

Manganate, cobaltate and ruthenate are the three most studied magnetic perovskites. The exchange interaction stiffness J , characterized by the Curie temperature ($J \sim 3/2k_B T_C$), can be tuned by manipulating the oxygen octahedral rotation^[94]. In addition, the OOR can cause the orbital occupation of B-site ions to realize the modulation of magnetic anisotropy^[95]. The magnetic easy axis switching of LSMO films grown on NGO substrates can be achieved by inserting a nonrotating STO ($a^0a^0a^0$) buffer layer^[33]. As shown in Fig. 7a, the easy axis of the nonbuffered LSMO is the a -axis, in strong contrast to the observed b -axis easy axis in the thick one. By inserting the STO buffer layer, the easy axis of the LSMO can be switched

to the b -axis again. Fig. 7b and 7c demonstrate the easy axis switching of LSMO films after being buffered by 1 u.c. and 9 u.c. STO buffer layers, respectively. To further determine the magnetization distribution of Mn, resonant X-ray reflection (RXR) was used to probe the magnetic profile of LSMO (6 u.c.) film without the STO buffer layer and that with 9 u.c. STO buffer layer (Fig. 7d). The spatial distribution of Ga, Ti, and Mn atoms demonstrates the atomic-level flat heterointerface. The decay length of octahedral rotation here is 2 nm, so it still exists on the surface of the LSMO film with a thickness of 6 u.c. Compared with the LSMO film without a buffer layer, the one buffered by STO has a smaller OOR (see Fig. 7d), thus exhibiting a more uniform magnetic profile and

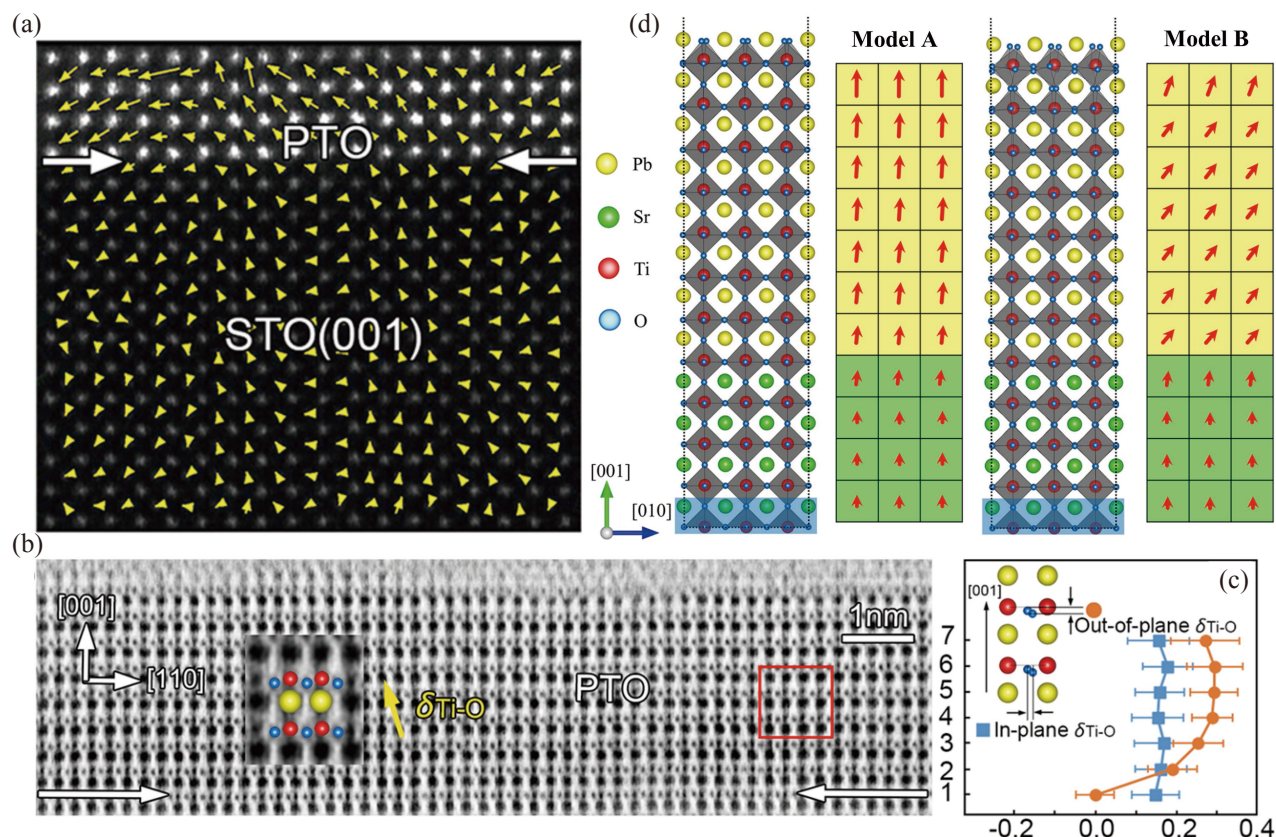


Fig. 6. Rotation of electric polarization induced by oxygen octahedral rotation. (a) HAADF-STEM image of the 1.6 nm thick PTO film and the electric polarization distribution. (b) are the ABF-STEM results. (c) Magnitude ($\delta_{\text{Ti-O}}$) of Ti^{4+} deviated from the oxygen octahedra center in- and out-of- plane of the 3.2 nm PTO film, respectively. (d) First-principles calculation results, where Model A and Model B give the relaxed atomic configuration with and without AFD, respectively. And the results of the electrical polarization simulation are shown on the right. Figure taken from Ref. [39].

a smaller thickness of the surface magnetic dead layer. This result in turn explains the enhanced saturation magnetization exhibited in Fig. 7b and 7c. The different saturation magnetization and magnetic anisotropy switching caused by the inserted STO buffer layer can be attributed to the difference in the hybridization strength between O 2p and Mn 3d caused by different OOR modes and amplitudes^[94].

Meanwhile, Kan et al.^[16] discovered the modulation of magnetic anisotropy mediated by OOR in the $\text{SRO}/\text{Ca}_{0.5}\text{Sr}_{0.5}\text{TiO}_3/\text{GaScO}_3$ heterostructure, and realized the switching of the magnetic easy axis of SRO. Subsequently, Zhang et al.^[96] constructed an $\text{LSMO}/\text{LaCoO}_{2.5}$ interface with a large symmetry mismatch, and strong perpendicular magnetic anisotropy was observed. Meng et al.^[97] observed the suppressed $[\text{RuO}_6]$ octahedral rotation caused by proximity $[\text{TiO}_6]$ octahedral couple at the interface of the $\text{BTO}/\text{SRO}/\text{BTO}$ heterostructure. Enhanced ferromagnetism and metallicity as well as Ru^{4+} displacement polarization in the sandwich were demonstrated by STEM, transport and magnetic characterization, demonstrating the coexistence of ferromagnetism-metal-polarization tristate in the SRO layer.

4 Summary and perspective

The physical properties of ABO_3 perovskite oxides are strongly related to the structure of the oxygen octahedral network, and the controllable design can be achieved by adjusting the size and shape of the $[\text{BO}_6]$ octahedral unit, as well as

the OOR mode and amplitude. At present, there are two common methods to control the OOR mode: interfacial strain engineering and symmetry mismatch coupling. For the former, the additional strain effect, not just OOR, has a manifesting contribution to tailor the properties as well. The latter, i.e., interface octahedral coupling, it has received much attention in recent years. The OOR can affect physical properties from two aspects. On the one hand, emergent physical properties can be generated by intertwining with the charge, spin, and orbital degrees of freedom; on the other hand, its original physical properties, such as magnetization or electric polarization, can be enhanced or improved to an unexpected level.

Benefiting from the rapid development of thin film growth technology, artificial oxide materials with complex interfacial structures and different lattice symmetries can be prepared. Conducting atomic-level analysis using techniques such as STEM can be a route to understand the key relationship between OOR and material processing. Importantly, designing the OOR at the atomic level is a controllable strategy to locate many functional oxides to phase boundaries, so as to capture obvious and emergent functional responses induced by external fields (electric, magnetic, and stress fields). In this paper, several typical examples, including, controlled electro- and magneto- transport, electrical polarization, and magnetism are presented. However, to develop and realize device applications utilizing the OOR effect, it is crucial to understand the following fundamental issues: How can the

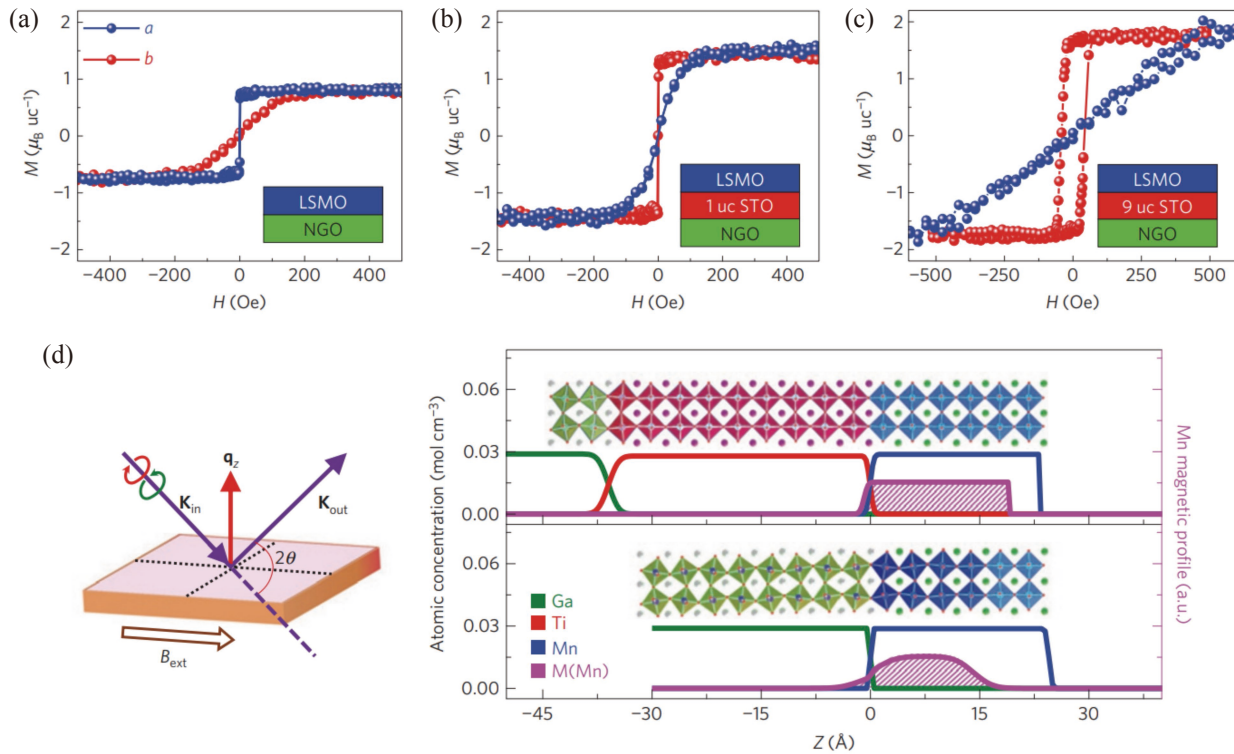


Fig. 7. Magnetic anisotropy in the magnetic heterojunctions. (a)–(c) show the M-H curves of the LSMO film along the a -axis and b -axis of the NGO substrate, where (a), (b), and (c) show the results of inserting 0 u.c., 1 u.c., and 9 u.c. STO buffer layers, respectively. (d) RXR measurements of 6 u.c. LSMO films with (top panel) and without (bottom panel) a 9 u.c. STO buffer layer showing depth profiles of the Ga, Ti, and Mn atomic concentration (green, red, and blue lines, respectively) and Mn magnetization (M , purple line with shaded area) at 20 K. The schematic on the left shows the experimental set-up used to perform RXR measurements, where a 0.6 T magnetic field was applied in-plane along the magnetic easy axis during the measurement. Figure taken from Ref. [33].

OOR be quantitatively predicted and described in thin films at heterointerfaces with arbitrary symmetry mismatch? What are the key parameters and mechanisms that determine the relaxation length of OOR coupling? Is it possible to independently manipulate the octahedral behavior along the in-plane and out-of-plane directions? Resolving these key issues is beneficial to further understand the OOR behavior and predict the physical properties of materials. Through subtle design, the functional properties of complex oxide heterostructures and devices can be tuned and developed.

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Conflict of interest

The authors declare that they have no conflict of interest.

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